

MBRF10H100CT-MBRF10H200CT

Isolated 10.0AMP. Schottky Barrier Rectifiers

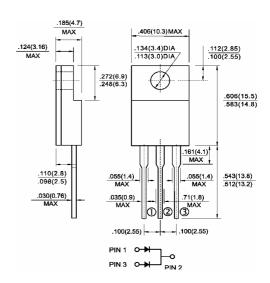
Features

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

Mechanical Data

- Cases: ITO-220AB molded plastic
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 5 in. lbs. max Weight: 0.08 ounce, 2.24 grams

ITO-220AB



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 10H100CT	MBRF 10H150CT	MBRF 10H200CT	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	100	150	200	V
Maximum RMS Voltage	V_{RMS}	70	105	140	V
Maximum DC Blocking Voltage	V_{DC}	100	150	200	V
Maximum Average Forward Rectified Current at T _C =125°C	I _(AV)	10			А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at Tc=133°C	I _{FRM}	10			А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	120			Α
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	1.0 0.5		Α	
$\label{eq:maximum Instantaneous Forward Voltage at (Note 2)} \begin{array}{l} I_F=5A,Tc=25^{\circ}C\\ I_F=5A,Tc=125^{\circ}C\\ I_F=10A,Tc=25^{\circ}C\\ I_F=10A,Tc=125^{\circ}C \end{array}$	V _F	0.85 0.75 0.95 0.85	0.75 0.95 0.97		V
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage @Tc=25 °C @ Tc=125 °C	I _R	5.0 1.0			uA mA
Voltage Rate of Change, (Rated V _R)	dV/dt	10,000			V/uS
$\begin{array}{ll} \text{RMS Isolation Voltage (t=1.0 second, R.H.} \\ \leq & 30\%, T_{\text{A}} = 25^{\circ}\text{C}) & \text{(Note 4)} \\ & \text{(Note 5)} \\ & \text{(Note 6)} \end{array}$	V _{ISO}	4500 3500 1500			V
Typical Thermal Resistance Per Leg (Note3)	R ₀ JC	3.5			°C/W
Operating Junction Temperature Range	$T_{\rm J}$	-65 to +175			°C
Storage Temperature Range	Tstg	76 -65 to +175			°C

Notes:

- 1. 2.0 us Pulse Width, f=1.0 KHz
- 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
- 3. Thermal Resistance from Junction to Case Per Leg.
- 4. Clip Mounting (on case), where lead does not overlap heatsink with 0.110" offset.
- 5. Clip mounting (on case), where leads do overlap heatsink.
- 6. Screw mounting with 4-40 screw, where washer diameter is \leq 4.9 mm (0.19")



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RATINGS AND CHARACTERISTIC CURVES (MBRF10H100CT - MBRF10H200CT)

